



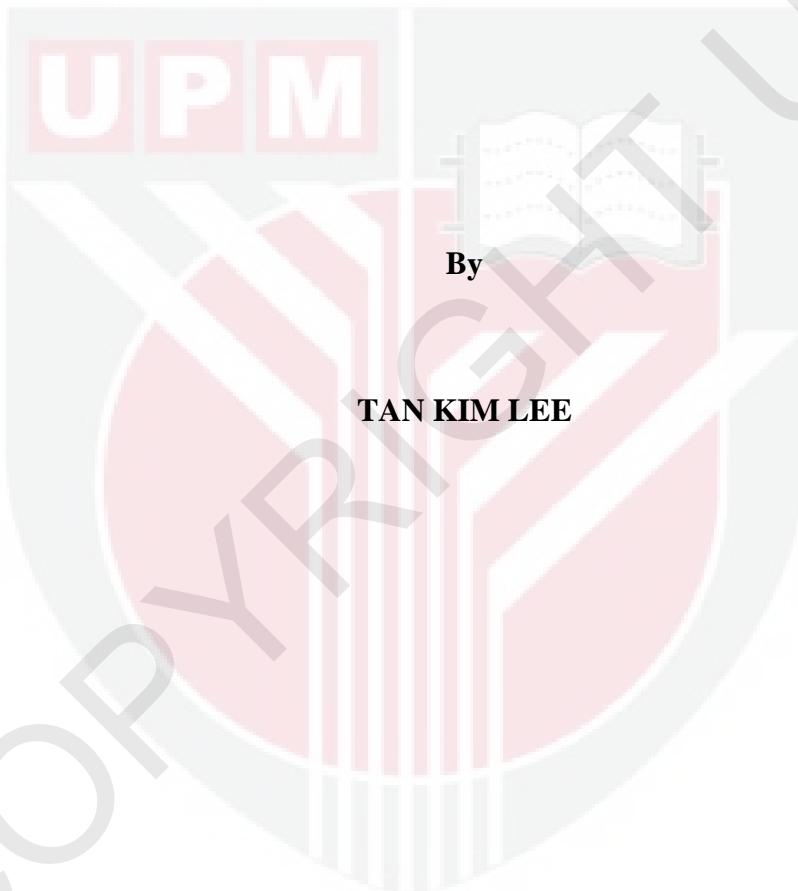
**UNIVERSITI PUTRA MALAYSIA**

**OPTIMISATION OF THE SUPERCONDUCTING PROPERTIES OF MgB<sub>2</sub>  
PREPARED BY THE REACTION OF (MgB<sub>4</sub> + Mg) AND DOPING WITH  
SILICON CARBIDE**

**TAN KIM LEE**

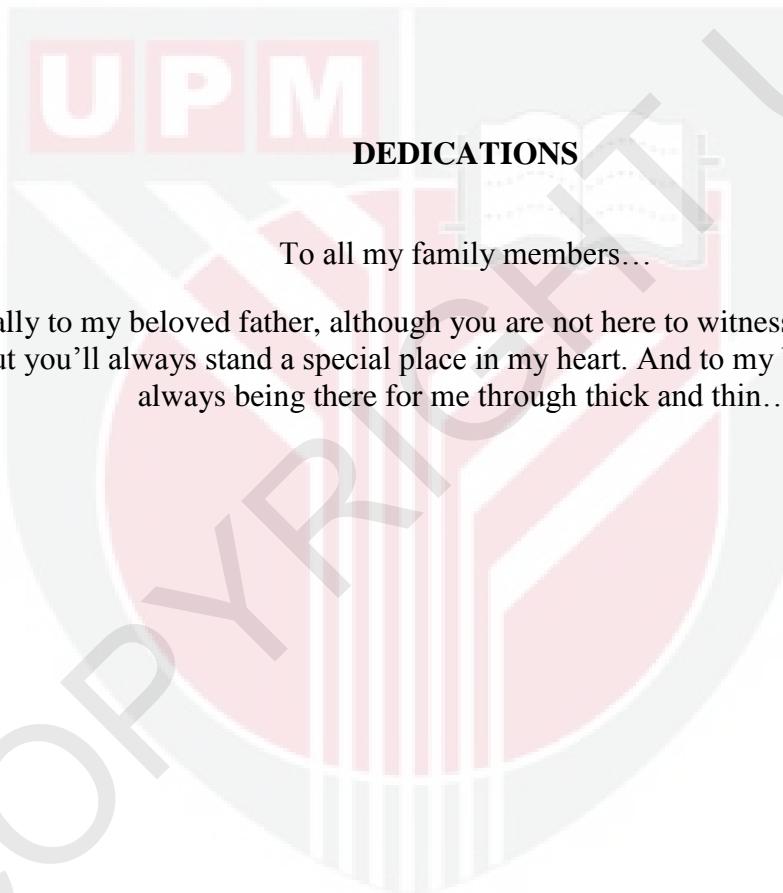
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**Thesis Submitted to the School of Graduate Studies, Universiti Putra Malaysia, in  
fulfillment of the Requirements for the Degree of Master of Science**

**December 2011**



To all my family members...

Especially to my beloved father, although you are not here to witness my achievements today but you'll always stand a special place in my heart. And to my beloved mother, for always being there for me through thick and thin...

*In loving memory of,  
Mr. Tan Thoo Yoong*

*"In order to reach the summit, you need to walk step by step"*

Abstract of thesis presented to the Senate of Universiti Putra Malaysia in fulfillment of the requirement for the degree of Master of Science.

**OPTIMISATION OF THE SUPERCONDUCTING PROPERTIES OF MgB<sub>2</sub>  
PREPARED BY THE REACTION OF (MgB<sub>4</sub> + Mg) AND DOPING WITH  
SILICON CARBIDE**

By

**TAN KIM LEE**

**December 2011**

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**Faculty : Science**

In this work, MgB<sub>2</sub> was synthesized by reaction of (MgB<sub>4</sub> + Mg) and the superconducting properties of the samples were optimized by using the following routes:

(i) variation of heat treatment, (ii) addition of excess Mg and (iii) addition of nano-SiC.

The porosity of the samples was much reduced as compared to the sample prepared by reaction of (Mg + 2B). The samples were analyzed through XRD, SEM, physical density and superconducting properties measurements.

Firstly, MgB<sub>4</sub> powder was synthesized by direct reaction of Mg and B. Between HNO<sub>3</sub>

and HCl, the use of the former for immersing time of 5 minutes was found to be effective in removing MgO phase in the MgB<sub>4</sub> sample sintered at 1050°C for 2 hours.

Hence, the MgB<sub>4</sub> powder with reduced amount of MgO was used as the precursor powders for the following reaction.

The phase transformation from MgB<sub>4</sub> to MgB<sub>2</sub> was done by reacting MgB<sub>4</sub> and Mg powders at the temperature range from 650°C to 950°C for 4 hours and 8 hours, respectively. The estimated weight fraction of MgB<sub>2</sub> is the highest at 650°C and 750°C but it decreased above 850°C and upon increasing the sintering time, it changed slightly. With increasing sintering temperature, the transition temperature T<sub>c</sub> decreased due to the lattice distortion of MgB<sub>2</sub>. The sample sintered at 750°C for 4 hours showed the highest magnetic J<sub>c</sub> ( $4.23 \times 10^4$  A/cm<sup>2</sup>) at 5 K and 2 T which is consistent with the highest weight fraction of MgB<sub>2</sub>.

Excess Mg powder was added into MgB<sub>4</sub> to synthesize nominal Mg<sub>x</sub>B<sub>2</sub> ( $x = 1.2, 1.5$  and 1.7) at 650°C and 750°C, respectively for 8 hours. The estimated weight fraction of MgB<sub>2</sub> decreased upon increasing  $x$  level and it increased with the sintering temperature. However, the effect of excess magnesium and sintering temperature on T<sub>c</sub> was not pronounced. With increasing  $x$ , Mg<sub>1.7</sub>B<sub>2</sub> sample sintered at 650°C showed the highest J<sub>c</sub> ( $7.59 \times 10^4$  A/cm<sup>2</sup>). Meanwhile at 750°C, Mg<sub>1.5</sub>B<sub>2</sub> sample recorded the highest J<sub>c</sub> ( $4.49 \times 10^5$  A/cm<sup>2</sup>), both at 5 K, 2 T. The J<sub>c</sub> was enhanced by higher estimated weight fraction of MgB<sub>2</sub> and the flux pinners (excess Mg).

In order to study the influence of nano-particle on J<sub>c</sub>, 2 wt. %, 5 wt. % and 10 wt. % of nano-SiC were added into the samples with nominal composition of Mg<sub>1.5</sub>B<sub>2</sub> and sintered at 750°C for 4 hours. The estimated weight fraction of MgB<sub>2</sub> decreased with SiC addition level. The *a*-axis decreased significantly indicating an increase in the C substitution at the B site upon increasing SiC addition level. Hence, T<sub>c</sub> degraded with

increasing SiC addition level due to the distortion of MgB<sub>2</sub> lattice. The highest J<sub>c</sub> of 1.52 × 10<sup>4</sup> A/cm<sup>2</sup> achieved by MgB<sub>2</sub> added with 2 wt. % of SiC were due to the C substitution that enhanced the scattering of the charge carrier and hence improved the field dependent J<sub>c</sub> behavior.

This work demonstrated that inexpensive way of using excess Mg as compared to SiC, could result in samples with higher value of J<sub>c</sub> (5 K, < 5 T) but SiC showed weaker field dependence of J<sub>c</sub>.

Abstrak tesis yang dikemukakan kepada Senat Universiti Putra Malaysia sebagai  
memenuhi keperluan ijazah Master Sains

**PENGOPTIMUMAN SIFAT SUPERKONDUKTOR MgB<sub>2</sub> YANG DISEDIAKAN  
DARIPADA TINDAK BALAS ANTARA (MgB<sub>4</sub> + Mg) DAN PENAMBAHAN  
SILICON CARBIDE**

Oleh

**TAN KIM LEE**

**Disember 2011**

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Dalam kerja ini, MgB<sub>2</sub> disintesis daripada tindak balas (MgB<sub>4</sub> + Mg). Sifat-sifat superkonduktor sampel telah dioptimumkan dengan menggunakan cara berikut: (i) perubahan rawatan haba, (ii) penambahan Mg berlebihan (iii) penambahan nano-SiC. Kelebihan kerja ini adalah keliangan sampel telah berkurangan berbanding dengan sampel yang disediakan melalui tindak balas (Mg + 2B). Sampel dianalisis melalui XRD, SEM, ketumpatan jisim dan pengukuran sifat superkonduktor.

Pertama, serbuk MgB<sub>4</sub> disintesis daripada tindak balas langsung antara Mg dan B. Antara HNO<sub>3</sub> dan HCl, perendaman serbuk MgB<sub>4</sub> dalam HNO<sub>3</sub> selama 5 minit didapati berkesan dalam menghapuskan fasa MgO di dalam sampel MgB<sub>4</sub> yang disinter pada suhu 1050°C selama 2 jam. Oleh itu, serbuk MgB<sub>4</sub> ini dengan fasa MgO yang telah dikurangkan digunakan sebagai serbuk permulaan bagi tindak balas yang berikutnya.

Transformasi fasa daripada  $MgB_4$  ke  $MgB_2$  dilakukan dengan tindak balas antara  $MgB_4$  dan serbuk Mg pada julat suhu daripada  $650^{\circ}C$  kepada  $950^{\circ}C$  selama 4 jam dan 8 jam, masing-masing. Anggaran pecahan berat  $MgB_2$  yang tertinggi dicapai pada  $650^{\circ}C$  dan  $750^{\circ}C$  tetapi ia berkurangan apabila suhu melebihi  $850^{\circ}C$  dan apabila masa pensinteran ditingkatkan, ia berubah sedikit sahaja. Dengan peningkatan suhu pensinteran, suhu genting  $T_c$  berkurangan disebabkan oleh pengherotan kekisi  $MgB_2$ . Sampel yang disinter pada suhu  $750^{\circ}C$  selama 4 jam menunjukkan  $J_c (4.23 \times 10^4 A/cm^2)$  yang tertinggi pada 5 K dan 2 T yang konsisten dengan anggaran pecahan berat  $MgB_2$  yang tertinggi.

Serbuk Mg berlebihan ditambahkan ke dalam  $MgB_4$  untuk mensintesis sampel dengan komposisi nominal  $Mg_xB_2$  ( $x = 1.2, 1.5$  dan  $1.7$ ) pada  $650^{\circ}C$  dan  $750^{\circ}C$ , masing-masing selama 8 jam. Anggaran pecahan berat  $MgB_2$  menurun apabila tahap  $x$  ditingkatkan dan ia meningkat dengan suhu pensinteran. Walau bagaimanapun, kesan magnesium berlebihan dan suhu pensinteran terhadap  $T_c$  adalah tidak ketara. Dengan tahap  $x$  yang semakin meningkat, sampel  $Mg_{1.7}B_2$  yang disinter pada suhu  $650^{\circ}C$  menunjukkan  $J_c (7.59 \times 10^4 A/cm^2)$  yang tertinggi manakala pada suhu  $750^{\circ}C$ , sampel  $Mg_{1.5}B_2$  mencatatkan  $J_c (4.49 \times 10^5 A/cm^2)$  yang tertinggi, kedua-duanya pada 5 K, 2 T.  $J_c$  telah dipertingkatkan oleh anggaran pecahan berat  $MgB_2$  yang tertinggi dan pengepin fluks (Mg berlebihan).

Untuk mengkaji pengaruh nanopartikel pada  $J_c$ , 2 %, 5 % dan 10 % nano-SiC telah ditambahkan ke dalam sampel dengan komposisi nominal  $Mg_{1.5}B_2$  dan disinter pada suhu  $750^{\circ}C$  selama 4 jam. Anggaran pecahan berat  $MgB_2$  menurun dengan tahap penambahan SiC. Parameter kekisi  $a$  menurun dengan ketara dan ini menunjukkan

peningkatan dalam penggantian C di tapak B apabila tahap penambahan SiC ditingkatkan. Oleh itu,  $T_c$  menurun dengan peningkatan tahap penambahan SiC yang ia disebabkan oleh pengherotan kekisi  $MgB_2$ .  $J_c$  yang tertinggi iaitu  $1.52 \times 10^4$  A/cm<sup>2</sup> dicapai oleh  $MgB_2$  yang ditambah dengan 2 % SiC di mana penggantian C meningkatkan penyebaran pengangkut cas dan secara tidak langsung ia memperbaiki ciri-ciri pergantungan medan  $J_c$ .

Penyelidikan ini menunjukkan cara yang lebih murah dengan penggunaan Mg berlebihan berbanding dengan SiC, untuk menghasilkan sampel yang mempunyai nilai  $J_c$  yang lebih tinggi (5 K, < 5 T). Walaubagaimanapun, penambahan SiC menunjukkan pergantungan medan  $J_c$  yang lemah.

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I certify that a Thesis Examination Committee has met on 27 December 2012 to conduct the final examination of Tan Kim Lee on her thesis entitled “Optimisation of the Superconducting Properties of MgB<sub>2</sub> Prepared by Reaction of MgB<sub>4</sub> + Mg and Doping with SiC” in accordance with the Universities and University Colleges Act 1971 and the Constitution of the Universiti Putra Malaysia [P.U.(A) 106] 15 March 1998. The Committee recommends that the student be awarded the Master of Science.

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## **DECLARATION**

I declare that the thesis is my original work except for quotations and citations which have been duly acknowledged. I also declare that it has not been previously, and is not concurrently, submitted for any other degree at Universiti Putra Malaysia or at any other institution.

**TAN KIM LEE**

Date: 27 December 2011



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